

AMENDMENTS TO THE TITLE AND SPECIFICATION

IN THE TITLE:

Please amend the title as indicated below:

A SEMICONDUCTOR MEMORY AND INFORMATION STORAGE DEVICE HAVING ELECTRICALLY ERASABLE AND PROGRAMMABLE SEMICONDUCTOR MEMORY CELLS

IN THE SPECIFICATION:

On page 1, before the heading "BACKGROUND OF THE INVENTION," please insert the following heading and paragraph:

"CROSS-REFERENCE TO RELATED APPLICATIONS"

This is a continuation application of Serial No. 10/304,046, filed November 26, 2002, which is a continuation of application Serial No. 09/944,406, filed September 4, 2001; which is a continuation of Serial No. 09/537,722, filed March 22, 2000 (now USP 6,285,595); which is a continuation of Serial No. 09/085,173, filed May 28, 1998 (now USP 6,052,315), the entire disclosures of which are hereby incorporated by reference.